## The Claims

1. A light emitting device, comprising:

a semiconductor device that emits light having a wavelength in the range of 200 nm to 620 nm; and

a red phosphor comprising a vanadate combined with yttrium, gadolinium and/or lanthanum and activated with trivalent Eu<sup>3+</sup>, Sm<sup>3+</sup> and Pr<sup>3+</sup>, or any combination thereof, with or without Tb<sup>3+</sup> as a co-dopant.

- 2. The device of claim 1 in which the red phosphor absorbs light of a wavelength in the range of 240 nm to 550 nm and emits red light at a wavelength in the range of 580 nm to 700 nm.
- 3. The device of claim 1 containing at least one non- red phosphor in addition to said red phosphor.
- 4. The device of claim 1 containing a green phosphor and a blue phosphor in addition to said red phosphor.
- 5. The device of claim 1 in which said red phosphor has the formula:

Bi<sub>x</sub>Ln<sub>1-x</sub>VO<sub>4</sub>:A

where x = 0 to 1, Ln is an element selected from the group consisting of Y, La and Gd, and A is an activator selected from  $Eu^{3+}$ ,  $Sm^{3+}$  and  $Pr^{3+}$ , or any combination thereof, with or without  $Tb^{3+}$  as a co-dopant.

- 6. The device of claim 5 in which x is greater than 0 and less than 1.
- 7. The device of claim 6 in which x is 0.05 to 0.5.
- 8. The device of claim 5 including Tb<sup>3+</sup> as a co-dopant.
- 9. The device of claim 1 in which the semiconductor device is a GaN based device.

- 10. The device of claim 1 in which the semiconductor device is a vertical cavity surface emitting laser, a light emitting diode, or a laser diode.
- 11. The device of claim 10 in which the semiconductor device is a GaN based device.
- 12. The device of claim 11 in which the semiconductor device is a light emitting diode.
- 13. The device of claim 5 containing a green phosphor and a blue phosphor in addition to said red phosphor and in which said green phosphor is ZnS:Cu<sup>+</sup>,Al<sup>3+</sup>) and said red phosphor is BaMgAl<sub>10</sub>O<sub>17</sub>:Eu2<sup>+</sup>.
- 14. A light emitting semiconductor device, comprising:
- a GaN based light emitting diode that emits light having a wavelength in the range of 200 nm to 620 nm;

a red phosphor that absorbs light of a wavelength in the range of 240 nm to 550 nm and emits red light at a wavelength in the range of 580 nm to 700 nm, having the formula:

where x is 0.05 to 0.5, Ln is an element selected from the group consisting of Y, La and Gd, and A is an activator selected from Eu<sup>3+</sup>, Sm<sup>3+</sup> and Pr<sup>3+</sup>, or any combination thereof, with or without Tb<sup>3+</sup> as a co-dopant;

- a green phosphor; and a blue phosphor.
- 15. The device of claim 14 including Tb<sup>3+</sup> as a co-dopant.
- 16. The device of claim 14 in which said green phosphor is ZnS:Cu<sup>+</sup>,Al<sup>3+</sup>) and said blue phosphor is BaMgAl<sub>10</sub>O<sub>17</sub>:Eu2<sup>+</sup>.
- 17. A white light emitting phosphor combination, comprising:

a red phosphor comprising a vanadate combined with yttrium, gadolinium and/or lanthanum and activated with trivalent Eu<sup>3+</sup>, Sm<sup>3+</sup> and Pr<sup>3+</sup>, or any

combination thereof, with or without Tb3+ as a co-dopant;

- a green phosphor; and
- a blue phosphor.
- 18. The phosphor combination of claim 17 in which said red phosphor absorbs light of a wavelength in the range of 240 nm to 550 nm and emits red light at a wavelength in the range of 580 nm to 700 nm.
- 19. The phosphor combination of claim 17 in which said red phosphor has the formula:

where x = 0 to 1, Ln is an element selected from the group consisting of Y, La and Gd, and A is an activator selected from  $Eu^{3+}$ ,  $Sm^{3+}$  and  $Pr^{3+}$ , or any combination thereof, with or without  $Tb^{3+}$  as a co-dopant.

- 20. The phosphor combination of claim 19 in which x is greater than 0 and less than 1.
- 21. The phosphor combination of claim 20 in which x is 0.05 to 0.5.
- 22. The phosphor combination of claim 19 in which said red phosphor includes Tb<sup>3+</sup> as a co-dopant.
- 23. The phosphor combination of claim 19 in which said green phosphor is ZnS:Cu<sup>+</sup>,Al<sup>3+</sup>) and said blue phosphor is BaMqAl<sub>10</sub>O<sub>17</sub>:Eu2<sup>+</sup>.
- 24. A white light emitting phosphor combination,

a red phosphor that absorbs said light of a wavelength in the range of 240 nm to 550 nm and emits red light at a wavelength in the range of 580 nm to 700 nm, having the formula:

where x is 0.05 to 0.5, Ln is an element selected from the group consisting of Y, La and Gd, and A is an activator selected from Eu<sup>3+</sup>, Sm<sup>3+</sup> and Pr<sup>3+</sup>, or any combination thereof, with or without Tb<sup>3+</sup> as a co-dopant.;

- a green phosphor comprising ZnS:Cu<sup>+</sup>,Al<sup>3+</sup>); and a blue phosphor comprising BaMgAl<sub>10</sub>O<sub>17</sub>:Eu2<sup>+</sup>.
- 25. The phosphor combination of claim 24 in which said red phosphor includes Tb<sup>3+</sup> as a co-dopant.
- 26. A red phosphor that absorbs said light of a wavelength in the range of 240 nm to 550 nm and emits red light at a wavelength in the range of 580 nm to 700 nm, having the formula:

$$Bi_xLn_{1-x}VO_4:A$$

where x is greater than 0 and less than 1, Ln is an element selected from the group consisting of Y, La and Gd, and A is an activator selected from Eu<sup>3+</sup>, Sm<sup>3+</sup> and Pr<sup>3+</sup>, or any combination thereof, with or without Tb<sup>3+</sup> as a co-dopant.

- 27. The phosphor 26 in which x is 0.05 to 0.5.
- 28. The phosphor 26 in which in which said red phosphor includes Tb<sup>3+</sup> as a co-dopant.